SKNa 22



Stud Diode

Avalanche Diode

SKNa 22

Publish Data

Features

- Avalanche type reverse characteristic
- Reverse voltages up to 5000 V
- Hermetic metal case with ceramic insulator and extra long creepage distances
- Threaded stud ISO M6
- · Cooling via heatsinks
- SKN: Anode to stud

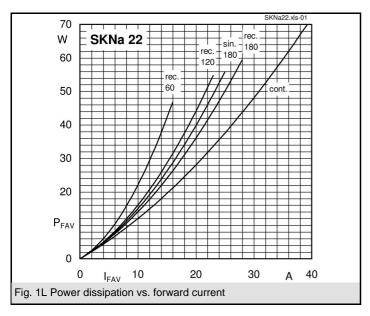
Typical Applications

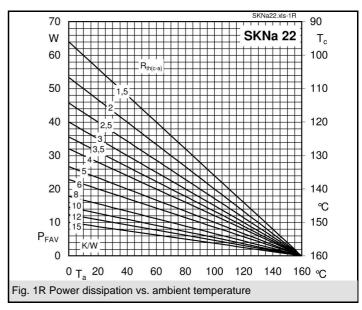
- High voltage rectifier diode for heavy duty applications
- Series connections for high voltage equipments like dust precipitators and high voltage power supplies
- Non-controllable and half-controllable rectifiers
- Free-wheeling diodes

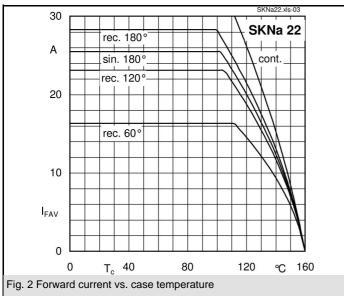
V _{(BR)min}	I _{FRMS} = 40 A (maximum value for continuous operation)	C _{max}	R_{min}
V	$I_{FAV} = 25 \text{ A (sin. 180; T}_{c} = 104 ^{\circ}\text{C})$	μF	Ω
3600	SKNa 22/36		
4000	SKNa 22/40		
4200	SKNa 22/42		
4500	SKNa 22/45		
4600	SKNa 22/46		
4800	SKNa 22/48		
5000	SKNa 22/50		

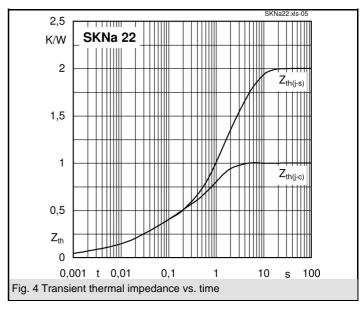
Symbol	Conditions	Values	Units
I _{FAV}	sin. 180 ; T _c = 104 (120) °C	25 (20)	Α
I _D	K 9; T _a = 45 °C; B2 / B6	16 / 23	А
	K 3; T _a = 45 °C; B2 / B6	28 / 40	Α
I _{FSM}	T _{vj} = 25 °C; 10 ms	450	Α
	T _{vi} = 160 °C; 10 ms	375	Α
i²t	T _{vj} = 25 °C; 8,3 10 ms	1000	A²s
	T _{vj} = 160 °C; 8,3 10 ms	700	A²s
V _F	T _{vj} = 25 °C; I _F = 60 A	max. 1,95	V
$V_{(TO)}$	T _{vi} = 150 °C	max. 1	V
r _T	T _{vi} = 150 °C	max. 20	mΩ
I_{RD}	$T_{vj} = 25 \text{ °C}; V_{RD} = V_{(BR)min}$	max. 300	μA
	$T_{vj} = 160 ^{\circ}\text{C}; V_{RD} = V_{(BR)min}$;	max. 3	mA
P_{RSM}	T_{vj} = 160 °C; t_p = 10 μ s	10	kW
R _{th(j-c)}		1	K/W
$R_{th(c-s)}$		1	K/W
T_{vj}		- 40 + 160	°C
T_{stg}		- 40 + 160	°C
V _{isol}		-	V~
M_s	to heatsink	2	Nm
		18	lb.in.
а		5 * 9,81	m/s²
m	approx.	25	g
Case		E 42	

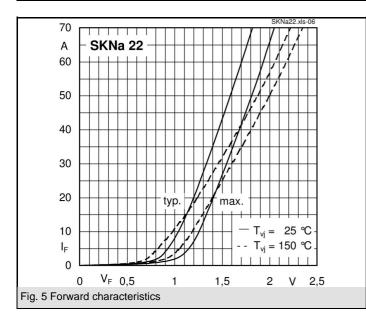


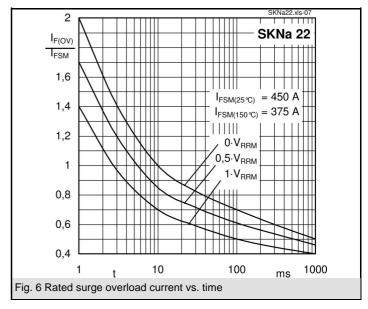




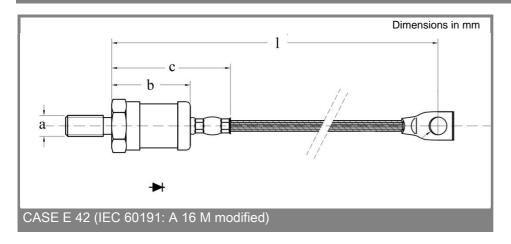








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